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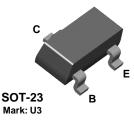
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**BSS64** 



**BSS64** 



### **NPN General Purpose Amplifier**

This device is designed for general purpose high voltage amplifiers and gas discharge display driving. Sourced from Process 16.

### Absolute Maximum Ratings\* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	80	V
V <sub>CBO</sub>	Collector-Base Voltage	120	V
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V
I <sub>C</sub>	Collector Current - Continuous	200	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах	Units
		*BSS64	
PD	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

\*Device mounted on FR-4 PCB 40 mm X 40 mm X 1.5 mm.

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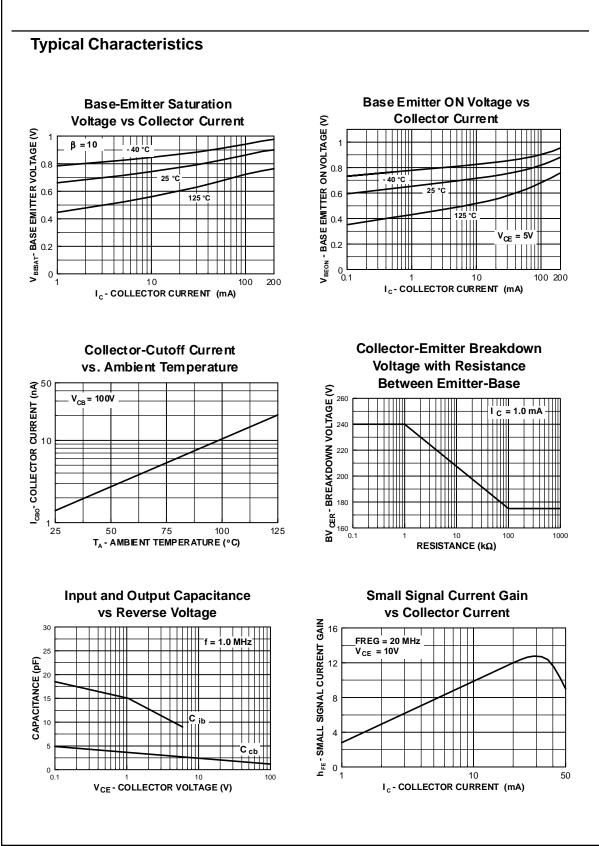
# NPN General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 4.0 \text{ mA}, I_{\rm B} = 0$	80		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$	120		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{\rm E} = 100 \mu {\rm A},  I_{\rm C} = 0$	5.0		V
Сво	Collector-Cutoff Current	$V_{CB} = 90 \text{ V}, \text{ I}_{E} = 0$		0.1	μA
1		$V_{CB} = 90 \text{ V}, \text{ I}_{E} = 0, \text{ T}_{A} = 150^{\circ}\text{C}$ $V_{EB} = 5.0 \text{ V}, \text{ I}_{C} = 0$		50	μA
EBO	Emitter-Cutoff Current	$v_{EB} = 5.0 v, I_C = 0$		200	nA
ON CHAR	ACTERISTICS				
h <sub>FE</sub>	DC Current Gain	$I_{C}$ = 10 mA, $V_{CE}$ = 1.0 V	20		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_{C} = 4.0 \text{ mA}, I_{B} = 400 \mu\text{A}$		0.15	V
	Base-Emitter Saturation Voltage	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 15 \text{ mA}$ $I_{\rm C} = 4.0 \text{ mA}, I_{\rm B} = 400 \mu \text{A}$		0.2	V
V <sub>BE(sat)</sub>	Dase Emilier Galdrailon Voltage	ις – 4.0 ma, iβ = 400 μA		1.2	v
	GNAL CHARACTERISTICS				
	Current Gain - Bandwidth Product	I <sub>C</sub> = 4.0 mA, V <sub>CE</sub> = 10,	60		MHz
F		$1_{\rm C} - 4.0$ $1_{\rm L}$ , $v_{\rm CE} = 10$ ,	00		
f <sub>T</sub>		f = 35 MHz			
C <sub>ob</sub> Spice NPN (Is=2 Ikr=0 Rc=	Output Capacitance Model 2.511f Xti=3 Eg=1.11 Vaf=100 Bf=242.6 =1 Cjc=4.883p Mjc=.3047 Vjc=.75 Fc= =8 Rb=10)	V <sub>CB</sub> = 10 V, f = 1.0 MHz 5 Ne=1.249 Ise=2.511f Ikf=.3458 2			
Cob Spice NPN (Is=2 Ikr=0 Rc= Vtf=5 Xtf	Model 2.511f Xti=3 Eg=1.11 Vaf=100 Bf=242.6 =1 Cjc=4.883p Mjc=.3047 Vjc=.75 Fc= =8 Rb=10)	V <sub>CB</sub> = 10 V, f = 1.0 MHz 5 Ne=1.249 Ise=2.511f Ikf=.3458 2		=3.197 Nc=	=2 lsc=0
Cob Spice NPN (Is=2 Ikr=0 Rc= Vtf=5 Xtf	Model         2.511f Xti=3 Eg=1.11 Vaf=100 Bf=242.6         21 Cjc=4.883p Mjc=.3047 Vjc=.75 Fc=         =8 Rb=10)         Al Characteristics         Typical Pulsed Current Gain	V <sub>CB</sub> = 10 V, f = 1.0 MHz 5 Ne=1.249 Ise=2.511f Ikf=.3458 2 5 Cje=18.79p Mje=.3416 Vje=.75 <b>Collector-E</b>	5 Tr=1.202	=3.197 Nc= n Tf=560p	-2 lsc=0 ltf=50m
Cob Spice NPN (Is=2 Ikr=0 Rc= Vtf=5 Xtf	Model 2.511f Xti=3 Eg=1.11 Vaf=100 Bf=242.6 =1 Cjc=4.883p Mjc=.3047 Vjc=.75 Fc= =8 Rb=10)	V <sub>CB</sub> = 10 V, f = 1.0 MHz 5 Ne=1.249 Ise=2.511f Ikf=.3458 2 5 Cje=18.79p Mje=.3416 Vje=.75 <b>Collector-E</b>	5 Tr=1.202	=3.197 Nc= n Tf=560p	-2 lsc=0 ltf=50m
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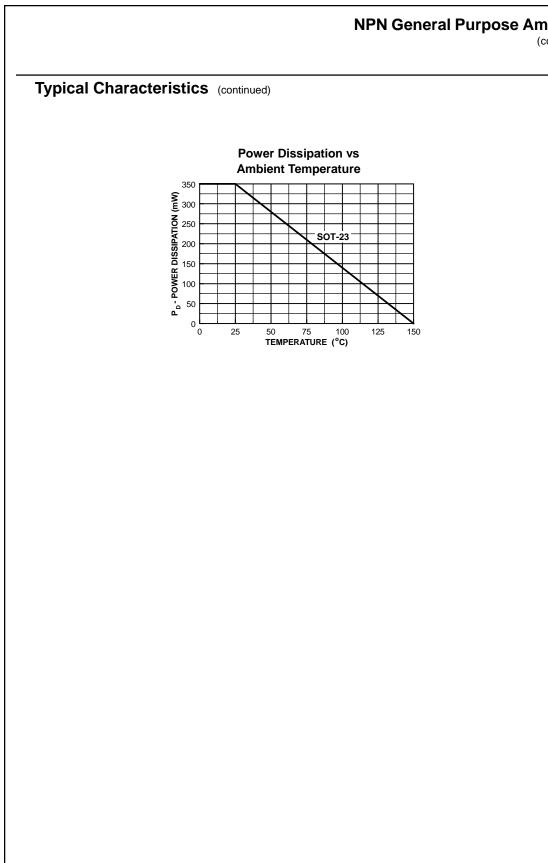
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#### NPN General Purpose Amplifier (continued)



# NPN General Purpose Amplifier (continued)



**BSS64** 

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